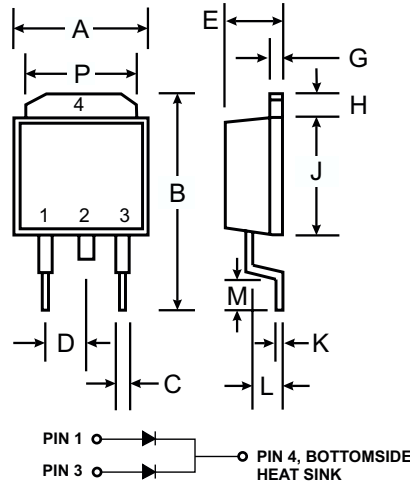


Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- Very Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, OR'ing, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: DPAK Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Marking: See Sheet 2
- Weight: 0.4 grams (approx.)
- Ordering Information: See Below



DPAK		
Dim	Min	Max
A	6.3	6.7
B	—	10
C	0.3	0.8
D	2.3 Nominal	
E	2.1	2.5
G	0.4	0.6
H	1.2	1.6
J	5.3	5.7
K	0.5 Nominal	
L	1.3	1.8
M	1.0	—
P	5.1	5.5
All Dimensions in mm		

Maximum Ratings @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	35	V
RMS Reverse Voltage	$V_{R(RMS)}$	25	V
Average Rectified Output Current (See Figure 4)	I_O	5 10	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load Per Package (JEDEC Method)	I_{FSM}	75	A
Typical Thermal Resistance Junction to Case Bottom Side Per Leg (Note 1)	$R_{\theta JC}$	2.43	°C/W
Voltage Rate of Change @ $V_R = 35V$, $T_j = 25^\circ C$	dv/dt	10,000	V/ μs
Operating Temperature Range	T_j	-55 to +125	°C
Storage Temperature Range	T_{STG}	-55 to +125	°C

Notes: 1. Device mounted on PC board with 14mm² (.013mm thick) copper pad areas.

Ordering Information (Note 2)

Device	Packaging	Shipping
MBRD1035CTL-T	DPAK	2500/Tape & Reel

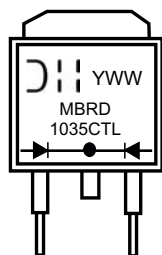
Notes: 2. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

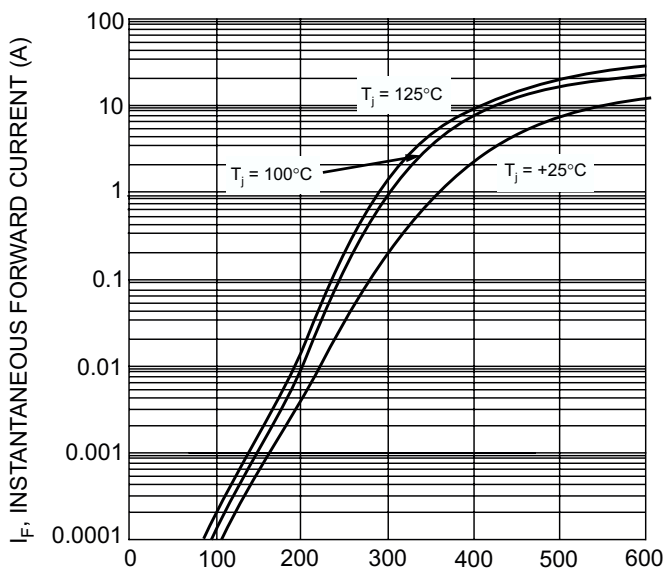
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	$V_{(BR)R}$	35	—	—	V	$I_R = 500\mu\text{A}$
Forward Voltage (Note 3)	V_{FM}	—	—	0.47 0.41 0.56 0.55	V	$I_F = 5\text{A}$, $T_S = 25^\circ\text{C}$ $I_F = 5\text{A}$, $T_S = 100^\circ\text{C}$ $I_F = 10\text{A}$, $T_S = 25^\circ\text{C}$ $I_F = 10\text{A}$, $T_S = 100^\circ\text{C}$
Peak Reverse Current (Note 3)	I_{RM}	—	0.04	2.0 30 200 5	mA mA μA mA	$V_R = 35\text{V}$, $T_J = 25^\circ\text{C}$ $V_R = 35\text{V}$, $T_J = 100^\circ\text{C}$ $V_R = 17.5\text{V}$, $T_J = 25^\circ\text{C}$ $V_R = 17.5\text{V}$, $T_J = 100^\circ\text{C}$
Typical Junction Capacitance	C_j	—	340	—	pF	$f = 1.0\text{MHz}$, $V_R = 4.0\text{V DC}$

- Notes:
1. Device mounted on PC board with 14mm^2 (.013mm thick) copper pad areas.
 2. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
 3. Short duration pulse test used to minimize self-heating effect.

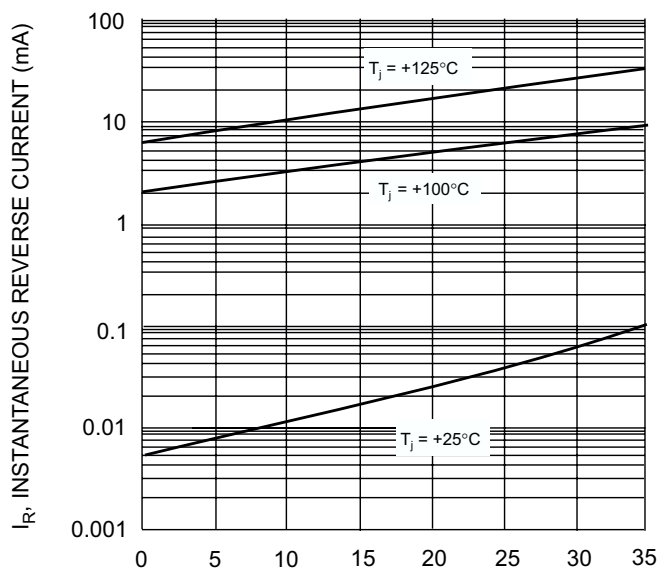
Marking Information



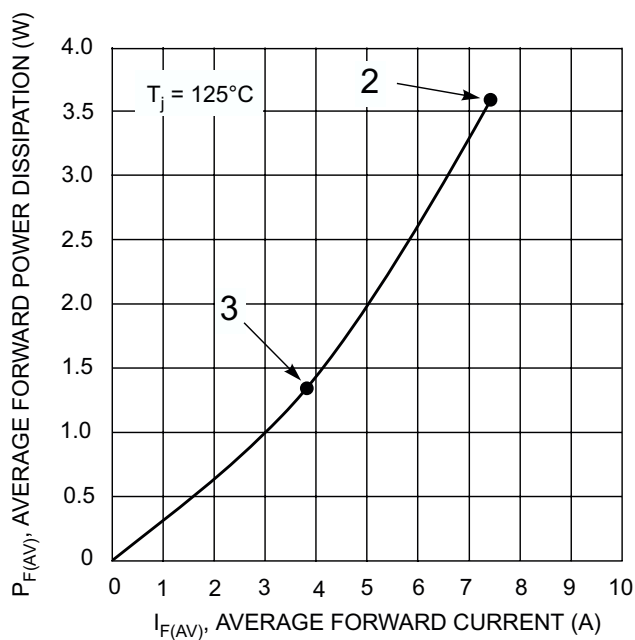
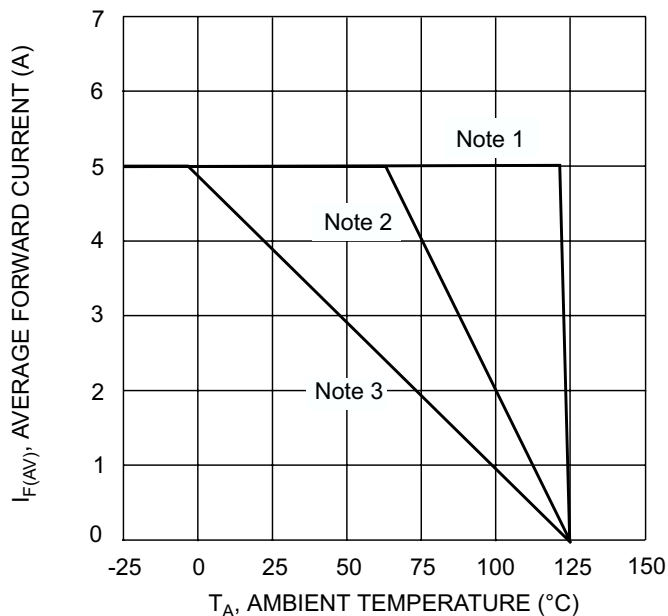
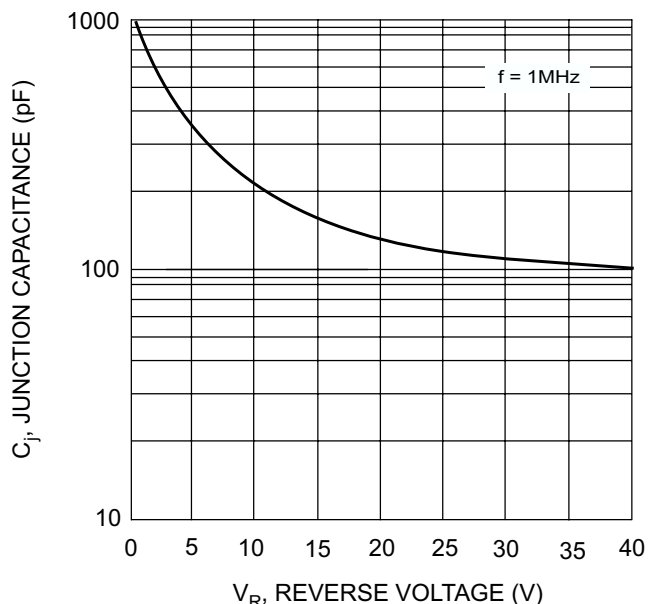
MBRD1035CTL = Product type marking code
 D11 = Manufacturers' code marking
 YWW = Date code marking
 Y = Last digit of year ex: 2 for 2002
 WW = Week code 01 to 52



V_F , INSTANTANEOUS FORWARD VOLTAGE (mV)
 Fig. 1 Typical Forward Characteristics (Per Element)



V_R , INSTANTANEOUS REVERSE VOLTAGE (V)
 Fig. 2 Typical Reverse Characteristics (Per Element)



- Notes:
1. $T_A = T_{\text{SOLDERING POINT}}$, $R_{\theta JC} = 2.43^\circ\text{C/W}$, $R_{\theta CA} = 0^\circ\text{C/W}$.
 2. Device mounted on GETEK substrate, 2"x2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". $R_{\theta JA}$ in range of 15-30°C/W.
 3. Device mounted on FR-4 substrate, 2"x2", 2 oz. copper, single-sided, pad layout as per Diodes Inc. suggested pad layout document AP02001 which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>. $R_{\theta JA}$ in range of 60-75°C/W.